

### 100V PNP HIGH PERFORMANCE TRANSISTOR IN POWERDI3333-8

### **Features**

- BV<sub>CEO</sub> > -100V
- Small Form Factor Thermally Efficient Package.
   Enables Higher Density End Products
- I<sub>C</sub> = -2A High Continuous Current
- I<sub>CM</sub> = -6A Peak Pulse Current
- Low Saturation Voltage V<sub>CE(sat)</sub> < -250mV @ -1A</li>
- Complementary NPN Type: DXTN07100BFG
- Rated to +175°C—Ideal For High Temperature Environment
- Wettable Flank For Improved Optical Inspection
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: PowerDI®3333-8
- Case Material: Molded Plastic. "Green" Molding Compound UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Solderable per MIL-STD-202, Method 208 (23)
- Weight: 0.03 grams (Approximate)

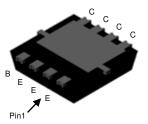
### **Applications**

- High Side Switch
- MOSFET or IGBT Gate Driving

PowerDI3333-8 (SWP) (Type UX)

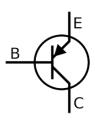


Top View



Bottom View

Equivalent Circuit



Device Symbol

# Ordering Information (Notes 4)

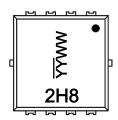
Ī	Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
	DXTP07100BFG-7	AEC-Q101	2H8	7	12	2000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**

PowerDI3333-8 (SWP) (Type UX)



2H8= Product Type Marking Code

YYWW = Date Code Marking

YY = Last Two Digits of Year (ex: 18 = 2018)

WW = Week Code (01 to 53)



# Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-120	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-100	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current	Ic	-2	Α
Peak Pulse Current	Ісм	-6	Α

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
	(Note 5)		0.9	W
Power Dissipation	(Note 6)	P <sub>D</sub>	2.1	W
	(Note 7)		3.1	W
	(Note 5)		140	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	R <sub>OJA</sub>	65	°C/W
	(Note 7)		44	°C/W
Thermal Resistance, Junction to Leads (Note 8	R <sub>OJL</sub>	8.5	°C/W	
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +175	°C	

## ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge—Human Body Model	ESD HBM	4000	V	3A
Electrostatic Discharge—Machine Model	ESD MM	400	V	С

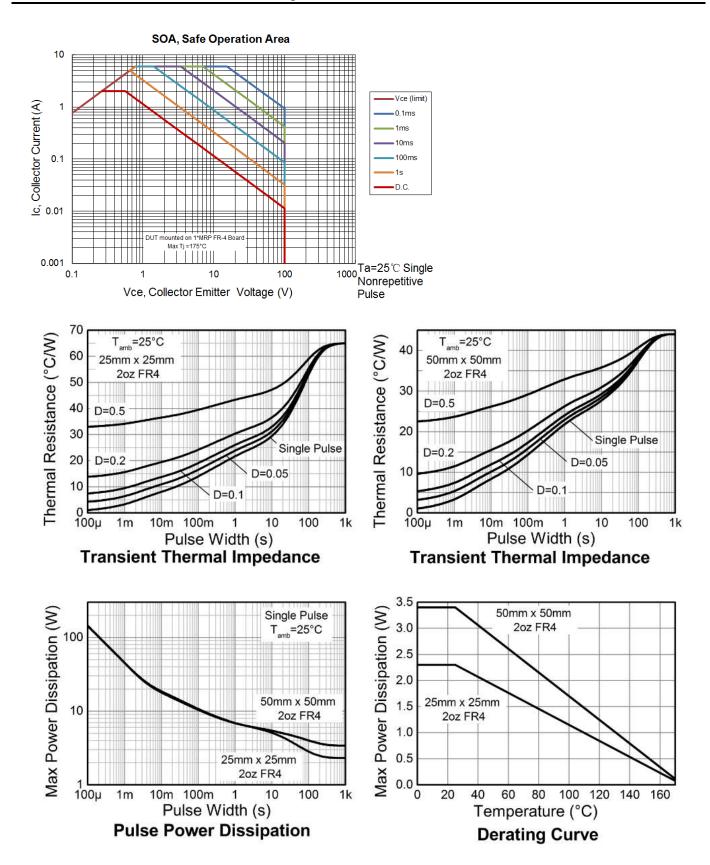
Notes:

- 5. For a device mounted with the collector tab on MRP FR4-PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as Note 5, except the device is mounted on 25mm × 25mm 2oz copper.

  7. Same as Note 5, except the device is mounted on 50mm × 50mm 2oz copper.
- 8. Thermal resistance from junction to solder-point (at the collector tab). 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



## **Thermal Characteristics and Derating Information**





# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

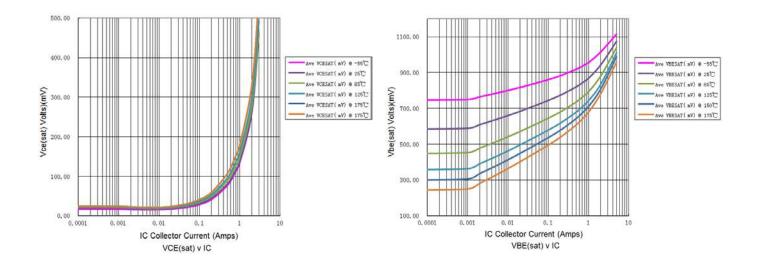
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-120	-170	_	V	$I_{C} = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 10)	BV <sub>CEO</sub>	-100	-124	_	V	I <sub>C</sub> = -10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	-8.4	_	V	I <sub>E</sub> = -100μA
Collector Cut-Off Current	·	_	_	-50	nA	V <sub>CB</sub> = -100V
Collector Gut-On Gurrent	I <sub>CBO</sub>	_	_	-10	μΑ	V <sub>CB</sub> = -100V, T <sub>A</sub> = +125°C
Emitter Cut-Off Current	I <sub>EBO</sub>	_	_	-20	nA	V <sub>EB</sub> = -6V
Collector-Emitter Saturation Voltage (Note 10)	V <sub>CE(sat)</sub>	_	-137	-250	mV	$I_C = -1A$ , $I_B = -100mA$
Collector-Emitter Saturation Voltage (Note 10)		_	-260	-500	mV	$I_C = -2A$ , $I_B = -200mA$
Base-Emitter Saturation Voltage (Note 10)	V <sub>BE(sat)</sub>	_	-0.87	-1	V	$I_C = -1A$ , $I_B = -100mA$
Base-Emitter Turn-On Voltage (Note 10)	V <sub>BE(on)</sub>	_	-0.78	-0.95	V	I <sub>C</sub> = -1A, V <sub>CE</sub> = -2V
	h <sub>FE</sub>	70	177	_	_	$I_C = -50 \text{mA}, V_{CE} = -2 \text{V}$
DC Current Goin (Note 10)		100	161	300	_	I <sub>C</sub> = -500mA, V <sub>CE</sub> = -2V
DC Current Gain (Note 10)		55	146	_	_	$I_C = -1A$ , $V_{CE} = -2V$
		25	53	_	_	$I_C = -2A$ , $V_{CE} = -2V$
Current Gain-Bandwidth Product	f⊤	100	140	_	MHz	V <sub>CE</sub> = -5V, I <sub>C</sub> = -100mA f = 100MHz
Turn-On Time	t <sub>on</sub>	_	40	_	ns	$V_{CC} = -10V, I_{C} = -500mA$
Turn-Off Time	t <sub>off</sub>	_	600	_	ns	$I_{B1} = -I_{B2} = -50 \text{mA}$
Output Capacitance	C <sub>obo</sub>	_	_	30	pF	V <sub>CB</sub> = -10V, f = 1MHz

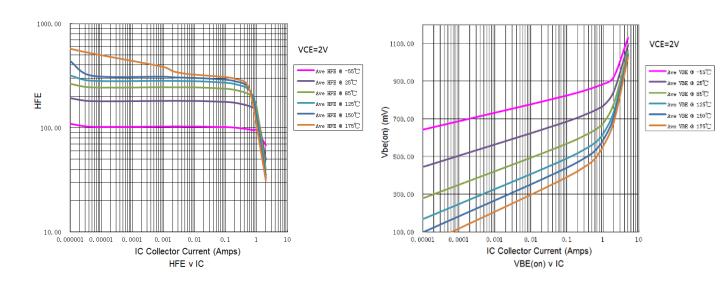
Note:

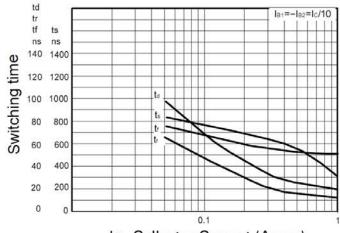
10. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.



# Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)







Ic - Collector Current (Amps)

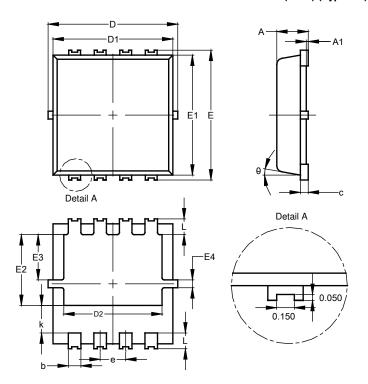
# **Switching Speeds**



# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### PowerDI3333-8 (SWP) (Type UX)

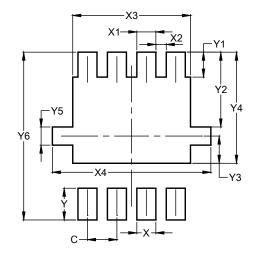


PowerDI3333-8 (SWP)						
(Type UX)						
Dim	Min	Max	Тур			
Α	0.75	0.85	0.80			
A1	0.00	0.05	_			
b	0.25	0.40	0.32			
С	0.10	0.25	0.15			
D	3.20	3.40	3.30			
D1	2.95	3.15	3.05			
D2	2.30	2.70	2.50			
Е	3.20	3.40	3.30			
E1	2.95	3.15	3.05			
E2	1.60	2.00	1.80			
E3	0.95	1.35	1.15			
E4	0.10	0.30	0.20			
е	_	_	0.65			
k	0.50	0.90	0.70			
L	0.30	0.50	0.40			
θ	0°	12°	10°			
All Dimensions in mm						

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### PowerDI3333-8 (SWP) (Type UX)



Dimensions	Value (in mm)
С	0.650
Х	0.420
X1	0.420
X2	0.230
Х3	2.600
X4	3.500
Υ	0.700
Y1	0.550
Y2	1.650
Y3	0.600
Y4	2.450
Y5	0.400
Y6	3.700

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.



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